



Reg. No. :

Name :

Third Semester B.Tech. Degree Examination, September 2014
(2008 Scheme)
(Special Supplementary)
08.305 : ELECTRONIC CIRCUITS – I (TA)

Time : 3 Hours

Max. Marks : 100

PART – A



Answer **all** questions.

1. Derive the expression for cut-off frequency of a low pass filter.
2. State and explain clamping circuit theorem.
3. Derive expression for rectification efficiency of a bridge rectifier.
4. Explain how you provide short circuit protection in a series voltage regulator.
5. Define various stability factors.
6. Draw the small signal model for a MOSFET at low and high frequencies.
7. Explain the voltage divider bias for enhancement MOSFETs.
8. A transistor in CB configuration offers more bandwidth than the same transistor in CE configuration. Explain.
9. Compare conversion efficiency and distortion of class A, AB, B and C amplifier circuits.
10. State and prove Miller theorem.

(10×4=40 Marks)

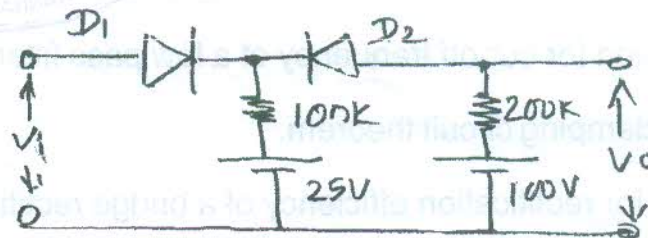


PART - B

Answer **two** questions from **each** Module. **All** questions carry **equal** marks.

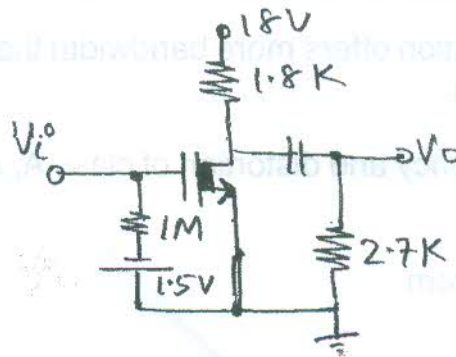
MODULE - I

11. A square of $\pm 5V$ amplitude and period T is applied to a low pass RC circuit with time constant $= 10 T$. Plot the output waveform to scale.
12. a) Derive expression for ripple factor in an LC filter connected to a full wave rectifier.
b) A single L - section filter is used to reduce the ripple of a full wave rectifier to 1%. Find the value of L , if the capacitance used is $16 \mu F$.
13. The input to the two level clipper shown varies linearly from 0 to 150 V. Sketch the output voltage to scale. Assume ideal diodes.



MODULE - II

14. Calculate the voltage gain of the amplifier for a device parameter $I_{DSS} = 10 \text{ mA}$ and $V_p = -4.5 \text{ V}$. Assume $r_d = \infty$. Derive the relevant expression.





15. Prove that for an emitter follower circuit the gain is approximately one and the input impedance is $R_B \parallel \beta R_E$.
16. Design an RC coupled amplifier for the following specifications : $A_V = -150$, $V_{CE(Q)} = 7\text{ V}$, $I_{C(Q)} = 2\text{ mA}$, $S = 4$; current gain of the transistor is 100 and supply voltage is 15 V.

MODULE – III



17. a) Write a note on biasing methods of class AB power amplifier.
b) Explain how cross over distortion occurs in class B power amplifier and the method to minimize it.
18. Draw the equivalent circuit at high frequencies for a CB amplifier. Determine high frequency poles. Comment on upper 3 dB frequency of the amplifier.
19. a) Compare the performance of CS and CD amplifiers.
b) Consider an amplifier with poles at 1 MHz and 2 MHz. The zeros are much higher than 2 MHz. Calculate the upper 3 dB frequency. **(6×10=60 Marks)**